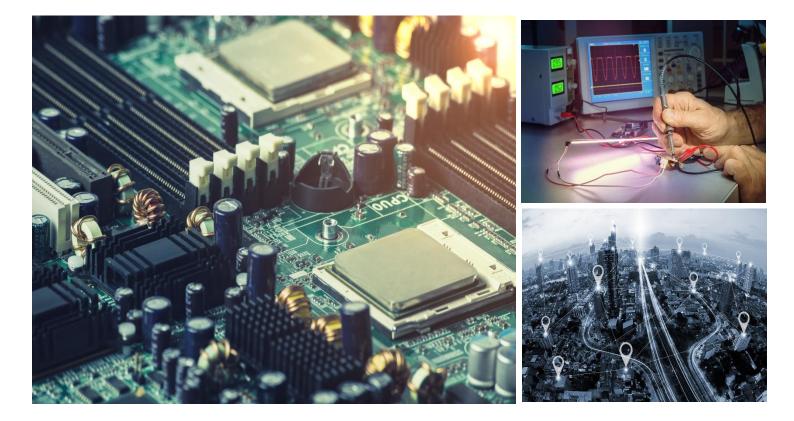
Model 670C | 180 MHz 600 MS/s Performance Arbitrary Waveform Generator





Features

- 2 or 4 Analog Channels
- 600 MS/s (1.2 GS/s with x2 interpolation)
- 16-bit Vertical Resolution
- Up to 12Vp-p into 50Ω load
- 180 MHz Bandwidth
- Up to 512 Mpts Waveform Memory per Channel
- 8 Digital Channels in synchronous with analog Generation

Applications

- Aerospace and Defense
- Institute and University Research
- Semiconductor Tests
- Automotive
- IoT



Model 670C | 180 MHz 600 MS/s Arbitrary Waveform Generator



Description

The Model 670C is a simple-to-use arbitrary waveform generator that operates on Windows based platform with 7" touch screen, front panel buttons and knob. The instrument has two operation modes - Simple Rider AFG (DDS AFG mode) and True Arb (variable clock Arbitrary AWG mode) which make the instrument easier to control. Model 670C supports the standard Ethernet interface for remote control and easy customized instrument programming.

The Model 670C comes with a 180 MHz arbitrary frequency generator and four analog channels operating up to 12 Vp-p into 50 Ω load impedance. An 8 digital output option is also available with each digital output providing up to a 600 Mb/s data rate in LVDS output format. The Model 670C also boasts a 1 S/s (Sample/second) to 600 MS/s (1 S/s to 1.2 GS/s with 2x interpolation) with 16-bit vertical resolution, providing outstanding signal integrity with a rise time/fall time of less than 1 ns.

Model 670C Front



Model 670C Rear





Model 670C User Interface

Simple Rider AFG: Function Generator Mode Interface

Simple Rider AFG UI is designed for touch and it has been developed to put all the capabilities of modern Waveform Generators right at your fingertips. All instrument controls and parameters are accessed through an intuitive UI that recalls the simplicity of Tablets and modern smart phones: touch features and gestures are available to engineers and scientists to create advanced waveforms or digital patterns in few touches.



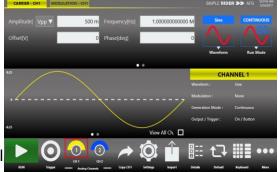
- The swipe gesture gives easy access to the output waveform parameters
- A touch-friendly virtual numeric keypad has been designed to improve the user experience on entering the data.
- Time saving shortcuts and intuitive icons simplify the instrument setup.

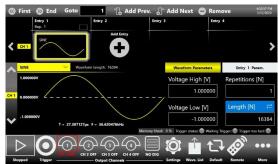
Simple Rider TrueArb: AWG and DPG Mode Interface

In **Simple Rider TrueArb** interface, the users can define complex waveforms with up to 16,384 sequence entries of analog waveforms and digital patterns, define their execution flow by means of loops, jumps and conditional branches.

Digital output combined and synchronized with analog output signals represent an ideal tool to troubleshoot and validate digital design. The waveform memory length of up to 512 Mpoints on each channel combined with up to 16,384 and up to 4,294,967,294 repetitions, make the Model 670C the ideal generator for the most demanding technical applications.

Thanks to the intuitive and easy waveform sequencer user interface, the most complex waveform scenarios can be created with just few screen touches.











•

Model 670C Applications

Automotive

Today's cars are including a lot of highly sophisticated electronic control unit with very sensitive electronic components. The Model 670C combining 600 MS/s (1.2 GS/s with 2x interpolation) with 16-bit vertical resolution, represents an ideal tool

for successfully addressing the new testing challenges in automotive.

- CAN, CAN-FD,LIN, Flexray,SENT emulation
- EMI debugging, troubleshooting, and testing
- Electrical standards emulation up to 12Vp-p
- Power MOSFET circuitry in automotive electronics optimization



IoT and Ind 4.0 Perfect RF Modulator

The Model 670C will be the iconic instrument for this application. The possibility to emulate complex RF I/Q modulation for simulation and Test vs wireless devices or working on Internet of things of industry 4.0 applications. Each engineer may use the possibility to import waveform to emulate devices under test, impose distortion on waveform (such noise) to test the ability of devices to be compliant to the standards.



Semiconductor Testing

Semiconductor engineers will also find the ability to emulate noisy or distorted waveforms useful for testing the compliance of their components. The fast edges and pulse generation of the Model 670C can be used to track the parameters of fast power devices.

- Clock and Sensor signals generation
- MOSFET gate drive amplitude signal emulation
- Power up sequences of IC using the low impedance feature (5 Ω output impedance)

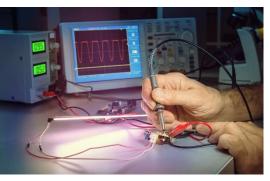




Research Applications

Research centers and universities are key users of the Model 670C, which can produce complex waveforms, multilevel signals, and pulse emulation based on variable edges. The Model 670C's combination of fast edge generation, excellent dynamic range and simple user interface meets the demands of scientists and engineers working on intensive experiments such as accelerators, tokamak, or synchrotrons, to emulate signals without creating specifics test boards.

- Emulation of detectors
- Emulation of signal sources adding noise
- Generation/playback of real-world signals
- Emulation of long PRBS sequences
- Modulating and driving laser diode



Aerospace and Defense applications

The Model 670C works perfectly with electronic warfare signals, such as those produced by Radar or Sonar systems. This generator can also be fitted into a modular system for radio or I/Q signal modulation, as well as create pulses useful in applications such as pulse electron beams, X-ray sources, flash X-ray radiography, lightning pulse simulators, and high power microwave modulators.

- Frequency response, intermodulation distortion and noise-figure measurements
- Phase Locked Loop (PLL) pull-in and hold range characterization
- Radar base-band signals emulation





Model 670C Specifications All specifications are typical unless noted otherwise. The guaranteed performances are referred to a calibrated instrument that has been stored for a minimum of 2 hours within the operating temperature range of 5°C to 40°C and after a 45-minute warm up period. Within ±10°C after auto-calibration

General Specifications			
Number of Channels	Model 670C-2C	Model 670C-4C	
Analog	2	4	
Digital Out	0 / 8 optional	0 / 8 optional	
Marker Out	1	1	
Operating Mode	AFG Mode True Arb Mode		
Amplitude			
Range (50 Ω into 50 Ω) ¹	0 to $6V_{p-p}$ (12 V_{p-p} optional)		
Accuracy (1kHz sine wave, 0V offset, $> 5mV_{p-p}$ amplitude, 50 Ω load) (guaranteed)	\pm (1% of setting [V _{p-p}] + 5 mV)	\pm (1% of setting [V _{p-p}] + 5 mV)	
Resolution	<0.5 mV _{p-p} or 5 digits		
Output impedance	Single-ended: 50 Ω, Low Impedance	e: 0 Ω	
DC			
Amplitude range (50 Ω into 50 Ω) ¹	-3 V to 3 V (-6 V to 6 V optional)		
Amplitude accuracy (guaranteed)	±(1% of setting + 10 mV)		
Output attenuator	0 dB or 20 dB selectable		
AFG Mode Specifications			
Output Channels			
Connectors	BNC on front panel		
Output type	Single-ended		
Output Impedance	50 Ω or 0 Ω (low impedance) progra	Immable	
General Specifications			
Operating mode	DDS mode	DDS mode	
Standard Waveforms		Sine, Square, Pulse, Ramp, more (Noise, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine)	
Run Modes	Continuous, modulation, sweep, but	Continuous, modulation, sweep, burst	
Arbitrary Waveforms	Vertical resolution: 16-bit Waveform length: 16,384 points		
Internal Trigger Timer Range Resolution Accuracy	13.4 ns to 100 s 104 ps ±(0.1% setting + 5 ps)		
	Model 670C-2C	Model 670C-4C	
Sine Waves			
Frequency Range Sine (50 Ω into 50 Ω)	$ \begin{array}{l} 1 \ \mu Hz \ to \leq 150 \ MHz: \ 6 \ V_{p \cdot p} \\ > 150 \ MHz \ to \leq 180 \ MHz: \ 5 \ V_{p \cdot p} \\ \underline{HV \ option:} \\ 1 \ \mu Hz \ to \leq 50 \ MHz: \ 12 \ V_{p \cdot p} \\ > 50 \ MHz \ to \leq 60 \ MHz: \ 10 \ V_{p \cdot p} \\ > 60 \ MHz \ to \leq 100 \ MHz: \ 8 \ V_{p \cdot p} \\ > 100 \ MHz \ to \leq 150 \ MHz: \ 6 \ V_{p \cdot p} \\ > 100 \ MHz \ to \leq 180 \ MHz: \ 5 \ V_{p \cdot p} \end{array} $		

¹ Amplitude doubles into HiZ load





Max Frequency Value	180 MHz	
Flatness (1 V_{p-p} , relative to 1 kHz)	DC to 180 MHz: ±0.5 dB	
Harmonic Distortion (1 V_{p-p})	1 μ Hz to \leq 20 kHz: <-75 dBc	
	>20 kHz to ≤ 1 MHz: <-70 dBc >1 MHz to ≤ 10 MHz: <-65 dBc	
	>10 MHz to \leq 50 MHz; <-55 dBc	
	$>50 \text{ MHz}$ to $\leq 120 \text{ MHz}$: <-45 dBc	
	>120 MHz to ≤ 180 MHz: <-40 dBc	
Total Harmonic Distortion (1 V _{p-p})	10 Hz to 20 kHz: < 0.04%	
Spurious (1 V _{p-p})	1 µHz to ≤ 10 MHz: <-80 dBc	
(excluding f _{Sa} - f _{out} , f _{Sa} - 2*f _{out})	>10 MHz to ≤ 180 MHz:	
	<-80 dBc + 6 dBc/octave	
Phase Noise (1 V _{p-p} , 10 kHz offset)	10 MHZ: < -127 dBc/Hz typ.	
	100 MHZ: < -115 dBc/Hz typ.	
Square Waves		
Frequency Range	1 μHz to 80 MHz: 6V _{p-p}	
	<u>HV option:</u> 1 μHz to ≤ 30 MHz: $12V_{PP}$	
	>30 MHz to \leq 50 MHz: 11V _{p-p}	
	>50 MHz to \leq 70 MHz: 10V _{p-p}	
	>70 MHz to \leq 80 MHz: 9V _{p-p}	
Rise/Fall Time	4 ns	
Overshoot (1 V _{p-p})	< 1%	
Jitter (rms)	< 2 ps	
Pulse Waves		
Frequency Range	1 μHz to 80 MHz: 6V _{p-p}	
	HV option:	
	1 μ Hz to \leq 3 MHz: 12V _{p-p}	
	>3 MHz to \leq 10 MHz: 11V _{p-p}	
	>10 MHz to ≤ 70 MHz: 10V _{p-p} >70 MHz to ≤80 MHz: 9V _{p-p}	
Pulse Width	5 ns to (Period - 5 ns)	
Pulse width Resolution	20 ps or 15 digits	
Leading/trailing edge transition time	4 ns to 1000 s	
Transition time Resolution	2 ps or 15 digits	
Pulse Duty Cycle	0% to 100%, 14 digits (limitations of pulse width apply)	
Overshoot (1 V _{p-p})	<1%	
Jitter (rms, with rise and fall time ≥4ns)	< 2 ps	
Double Pulse Waves		
Frequency Range	1 μHz to ≤ 3 MHz: 12V _{p-p}	
	>3 MHz to \leq 50 MHz: $6V_{p-p}$	
	where $V_{p-p} = V_{p-p}1 + V_{p-p}2 $	
	HV option:	
	1 μ Hz to \leq 3 MHz: 24V _{p-p}	
	>3 MHz to \leq 10 MHz: 11V _{p-p} >10 MHz to \leq 50 MHz: 10V _{p-p}	
	where $V_{p,p} = V_{p,p}1 + V_{p,p}2 $	
Other Pulse Parameters	Same as Pulse Waves	
Ramp Waves	Game as 1 USE WAVES	
Frequency Range	1 µHz to 5 MHz	
Linearity (< 10 kHz, 1 V_{p-p} , 100%)	≤ 0.1%	
Linearity (< 10 KHZ, 1 v_{p-p} , 100%)	- 0.1/0	





Symmetry	0% to 100%		
Other Waves			
Frequency Range			
Exponential Rise, Exponential Decay	1 µHz to 5 MHz		
Sin(x)/x, Gaussian, Lorentz, Haversine	1 μHz to 10 MHz		
Additive Noise			
Bandwidth (-3 dB)	> 200 MHz		
Level	0 V to 6 V – carrier max value $[V_{pk}]$		
Resolution	1 mV		
Arbitrary	0.1-40.004		
Number of Samples	2 to 16,384 1 μHz to ≤ 80 MHz		
Frequency range	87.5 MHz		
Analog Bandwidth (-3 dB)			
Rise/Fall Time	4 ns		
Jitter (rms)	< 2 ps		
Frequency Resolution			
Sine, square, pulse, arbitrary, Sin(x)/x	1 μHz or 15 digits		
Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine	1 μHz or 14 digits		
Frequency Accuracy			
Non-ARB	$\pm 2.0 \times 10^{-6}$ of setting		
ARB	$\pm 2.0 \text{ x} 10^{-6} \text{ of setting } \pm 1 \mu\text{Hz}$		
Modulations			
Amplitude Modulation (AM)			
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation Source	Internal		
Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB		
Modulating Frequency	500 µHz to 48 MHz		
Depth	0.00% to 120.00%		
Frequency Modulation (FM)			
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation Source	Internal		
Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB		
Modulating Frequency	500 µHz to 48 MHz		
Peak Deviation	DC to 180 MHz		
Phase Modulation (PM)			
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation Source	Internal		
Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB		
Modulating Frequency	500 µHz to 48 MHz		
Phase Deviation Range	0° to 360°		
Frequency Shift Keying (FSK)			
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation Source	Internal		
Internal Modulating Waveforms	Square		
Key Rate	500 µHz to 48 MHz		



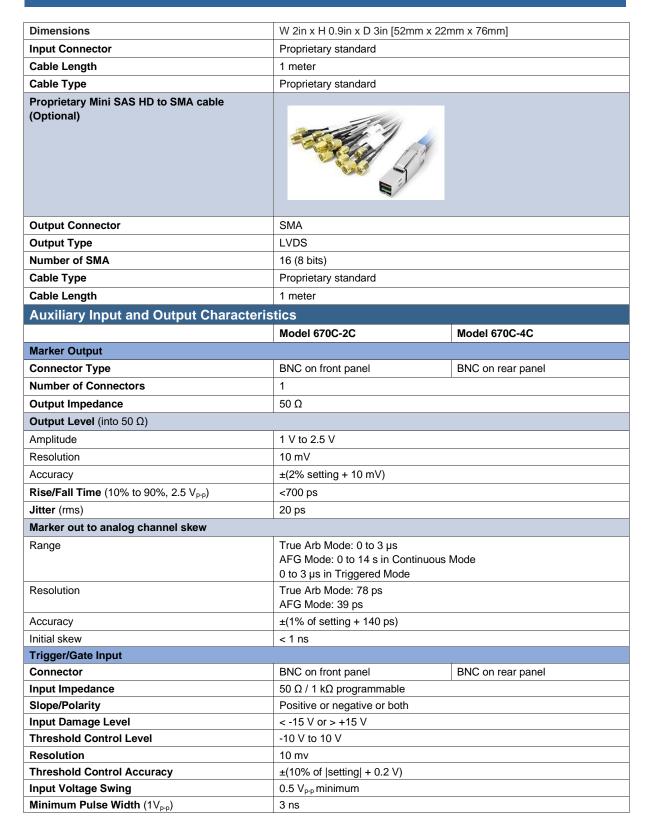
Hop Frequency	1 μHz to 180 MHz	
Number of Keys	2	
Phase Shift Keying (PSK)		
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB	
Modulation source	Internal	
Internal Modulating Waveforms	Square	
Key Rate	500 µHz to 48 MHz	
Hop Frequency	0° to +360°	
Number of Keys	2	
Pulse Width Modulation (PWM)		
Carrier Waveforms	Pulse	
Modulation Source	Internal	
Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB	
Modulating Frequency	500 µHz to 48 MHz	
Deviation Range	0% to 50% of pulse period	
Sweep		
Туре	Linear, Logarithmic, Staircase, and user defined	
Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB	
Sweep Time	40 ns to 2000 s	
Hold/return Times	0 to (2000 s - 40 ns)	
Sweep/Hold/Return Time Resolution	20 ns or 12 digits	
Total Sweep Time Accuracy	≤ 0.4%	
Start/Stop Frequency Range	Sine: 1 µHz to 180 MHz Square: 1 µHz to 80 MHz	
Trigger Source	Internal / External / Manual	
Burst		
Waveforms	Standard waveforms (except DC and Noise), ARB	
Туре	Triggered or Gated	
Burst Count	1 to 4,294,967,295 cycles or Infinite	
True Arb Mode Specifications		
Output Channels		
Connectors	BNC on front panel	
Output Type	Single-ended DC coupled	
Output Impedance	50 Ω or 0 Ω (low impedance)	
General specifications		
Operating Mode	Variable clock (True Arbitrary)	
Run Modes	Continuous, Triggered Continuous, Single/Burst, Stepped, Advanced	
Vertical Resolution	16 bit	
Waveform Length	16 to 2 MSamples per channel (up to 256 MSamples optional)	
Waveform Granularity	1 if the entry length is >384 samples 8 if entry length is ≥16 and ≤384 samples	
Sequence Length	1 to 16,384	
Sequence Repeat Counter	1 to 4,294,967,295 or infinite	
	۱ <u>ــــــــــــــــــــــــــــــــــــ</u>	



Timer Range Resolution		
Range	23.52 ns to 7 s	
Resolution	±1 sampling clock period	
Analog Channel to Channels skew		
Range	0 to 6.59 us (depending on internal sampling rate)	
Resolution	Channel 1/2 to Channel 3/4: ≤ 5 ps,	
	Channel 1/3 to Channel 2/4: 1 DAC sampling period	
Accuracy	±(1% of setting + 20 ps)	
Initial skew	< 200 ps	
Calculated bandwidth (0.35 / rise or fall time) ²	≥ 160 MHz	
Harmonic distortion (Sine wave 32 pts, 1 V_{p-p})	< -62 dBc (@ 600MS/s, 18.75 MHz)	
Spurious (Sine wave 32 pts, 1 V _{p-p}	< -80 dBc (@ 600MS/s, 18.75 MHz)	
SFDR (Sine wave 32 pts, 1 V_{p-p} , including Harmonics)	< -62 dBc (@ 600MS/s, 18.75 MHz)	
Rise/fall time (1 V_{p-p} single-ended 10% to 90%) ²	≤ 2.2 ns	
Overshoot (1 V _{p-p} single-ended) ²	< 2%	
Timing and Clock		
Sampling Rate	T	
Range	1 S/s to 600 MS/s (1 S/s to 1.2 GS/s with x2 interpolation)	
Resolution	16 Hz	
Accuracy	±2.0 ppm	
Random jitter on clock pattern (rms)	< 2 ps	
Digital outputs (Optional)		
Output Channels		
Connectors	Mini-SAS HD connector on rear panel (Non-standard pin-out)	
Number of connectors	1	
Number of outputs	8 bits	
Output impedance	100 Ω differential	
Output type	LVDS	
Rise/fall time (10% to 90%)	< 1 ns	
Jitter (rms)	20 ps	
Maximum update rate	600 Mbps	
Memory depth	2 MSamples per digital channel (up to 512MSamples	
8 bit LVDS to LVTTL Converter Probe (Optional AT-DLL8)		
Output Connector	20 position 2.54 mm 2 Row IDC Header	
Output Type	LVTTL	
Output Impedance	50 Ω nominal	
Output Voltage	0.8 V to 3.8 V programmable	
Maximum Update Rate	125 Mbps@0.8V and 400 Mbps@3.6V	

² 2x interpolation OFF







Initial Trigger/Gate Delay to Analog Output	AFG mode: <400 ns (<460 ns in triggered sweep mode) True Arb mode: <131*DAC sampling period + 22.5 ns	
	(<143*DAC sampling period+22.5 ns with 2x interpolation)	
Trigger In to Output Jitter	AFG mode: <45 ps	
55	True Arb mode: 0.29*DAC sampling period	
Maximum Frequency	AFG mode: 65 MTps on Rising/Falling Edge,	
	80 MTps on Both Edges	
	True Arb mode: 42.5 MTps	
Reference Clock Input	where MTps = Mega Transitions per second	
Connector Type	SMA on rear panel	
Input Impedance	50 Ω, AC coupled	
Input Voltage Range	-4 dBm to 11 dBm sine or square wave (rise time T10-90 <1ns and duty cycle from 40% to 60%)	
Damage Level	+14 dBm	
Frequency Range	5 MHz to 100 MHz	
Reference Clock Output		
Connector Type	SMA on rear panel	
Output Impedance	50Ω , AC coupled	
	10 MHz	
Frequency		
Accuracy	$\pm 2.0 \times 10e^{-6}$	
Aging	± 1.0 x 10e ⁻⁶ /year	
Amplitude	1.65 V	
Jitter (rms)	<20 ps	
Power		
Source Voltage and Frequency	100 to 240 VAC ±10% @ 45 Hz to 66 Hz	
Max. power consumption	100 W	
Environmental characteristics		
Temperature (operating)	+41 °F to 104 °F [+5 °C to +40 °C]	
Temperature (non-operating)	-4 °F to 140 °F [-20 °C to +60 °C]	
Humidity (operating)	5% to 80% relative humidity with a maximum wet bulb temperature of 84°F at or below +104°F, (upper limit de–rates to 20.6% relative humidity at +104°F). Non-condensing.	
Humidity (non-operating)	5% to 95% relative humidity with a maximum wet bulb temperature of 104°F at or below +140°F, upper limit de–rates to 29.8% relative humidity at +140°F. Non-condensing.	
Altitude (operating)	9,842 feet (3,000 meters) maximum at or below 77°F	
Altitude (non-operating)	39,370 feet (12,000 meters) maximum	
EMC and Safety	· · · · · · · · · · · · · · · · · · ·	
Compliance	CE compliant	
Safety	EN61010-1	
Main Standards	EN 61326-1:2013 – Electrical equipment for measurement, control and laboratory use – EMC requirements – Part 1: General requirements	
Immunity	EN 61326-1:2013	



System specifications			
	Model 670C-2C	Model 670C-4C	
Display	7", 1024x600, capacitive touch LCD	7", 1024x600, capacitive touch LCD	
Operative System	Windows 10	Windows 10	
External Dimensions	W 362 mm – H 143 mm – D 258 mr	W 362 mm – H 143 mm – D 258 mm (3U 10" rackmount)	
Weight	6.25 kg	6.25 kg	
Front panel connectors	CH1, CH2 OUTPUT (BNC)	CH1, CH2 OUTPUT (BNC)	
	MARKER OUT (BNC)	CH3, CH4 OUTPUT (BNC)	
	TRIGGER IN (BNC)		
Rear panel connectors	REF CLK IN (SMA)	REF CLK IN (SMA)	
	REF CLK OUT (SMA)	REF CLK OUT (SMA)	
	External Monitor ports	MARKER OUT (BNC)	
	DIGITAL POD A[70]	TRIGGER IN (BNC)	
	1 USB 2.0 ports or more	External Monitor ports	
	Ethernet port (10/100/1000BaseT	DIGITAL POD A[70]	
	Ethernet, RJ45 port)	1 USB 2.0 ports or more	
	2 PS/2 keyboard and mouse ports	Ethernet port (10/100/1000BaseT	
		Ethernet, RJ45 port)	
		2 PS/2 keyboard and mouse ports	
Hard Disk	240 GB SSD or better	240 GB SSD or better	
Processor	Intel® Celeron J1900, 2 GHz (or be	Intel® Celeron J1900, 2 GHz (or better)	
Processor Memory	4 GB or better	4 GB or better	